



Note: answer four questions

Q.1) Sketch the diagram of electron concentration versus temperature for silicon (n-type) that has been doped with 10^{21} m^{-3} of a donor impurity, and for intrinsic silicon, and then answer the following questions:

- 1) Determine the Freeze-out, Extrinsic and Intrinsic temperature regions on figure.
 - 2) Which of these temperate regions are the best for designing most solid-state devices? Why?
 - 3) What occurs to the electron concentration at freeze-out temperature region?
 - 4) Why termed the high end of temperature scale by intrinsic region?
 - 5) On the basis of Figure, as dopant level is increased would you expect the temperature at which a semiconductor becomes intrinsic to increase, to remain essentially the same, or to decrease? Why?
- (15marks)

Q.2:- A) If a metallic material is cooled through its melting temperature at an extremely rapid rate, it will form a noncrystalline solid (i.e., a metallic glass). Will the electrical conductivity of the noncrystalline metal be greater or less than its crystalline counterpart? Why?

(3marks)

Q.2:- B) For gaseous argon, solid LiF, liquid H_2O , and solid Si, what find(s) of polarization is (are) possible? Why?

(8marks)

Q.2:-C) A parallel-plate capacitor with dimensions of 38mm by 65mm and a plate separation of 1.3mm must have a minimum capacitance of ($7 \times 10^{-11} \text{ F}$) when an (ac) potential of (1000V) is applied at a frequency of 1MHz. Find the relative permittivity of the capacitance material.

(4marks)

Q.3:-A) What is the principle of magnetic levitated train? Which kind of material is used in its construction? Why?

(5marks)

Q3:-B) (1) Explain the two sources of magnetic moments for electrons. (2) Do all electrons have a net magnetic moment? Why or why not? (3) Do all atoms have a net magnetic moment? Why or why not?

(5marks)

Q.3:- C) After finding the electrical conductivity of cobalt at 0°C , we decide to double that conductivity. To what temperature must we cool the metal? Hence the resistivity at room temperature $6.24 \times 10^{-6} \Omega \cdot \text{cm}$ and $\alpha = 0.006 \Omega \cdot \text{cm}/^\circ\text{C}$.

(5marks)

Q.4:-A) Cite the differences between hard and soft magnetic materials in terms of both hysteresis behavior (characterization with sketch) and typical applications.

(10marks)

Q.4:-B) Nb_3Sn and GaV_3 are candidates for a superconductive application at the same critical magnetic field. Find the lower temperature for Nb_3Sn in order to be superconductive. Hence, GaV_3 ($H_0 = 350,000$ oersted, $T = 12.7\text{K}$, $T_C = 16.8\text{K}$), Nb_3Sn ($H_0 = 250,000$ oersted, $T_C = 18.05\text{K}$).

(5marks)

Q.5:-A) A light – emitting diode display made using a GaAs–GaP solid solution of composition 0.4 GaP–0.6 GaAs has a band gap of 1.9eV. What will be the color this LED display? Hit: used table (1), Plancks constant ($6.63 \times 10^{-34} \text{ J}\cdot\text{s}$, $4.14 \times 10^{-15} \text{ eV}\cdot\text{s}$), speed of light ($2.998 \times 10^8 \text{ m/s}$).

(3marks)

Q.5:-B) Briefly explain why the ferroelectric behavior of BaTiO_3 ceases above its ferroelectric Curie temperature. (4marks)

Q.5:-C) Figure (1) shows the B-versus-H curve for a nickel-iron alloy.

- (a) What is the saturation flux density?
- (b) What is the saturation magnetization?
- (c) What is the remanence?
- (d) What is the coercivity?

(8marks)

Figure (1): Complete magnetic hysteresis loop for a nickel-iron alloy.

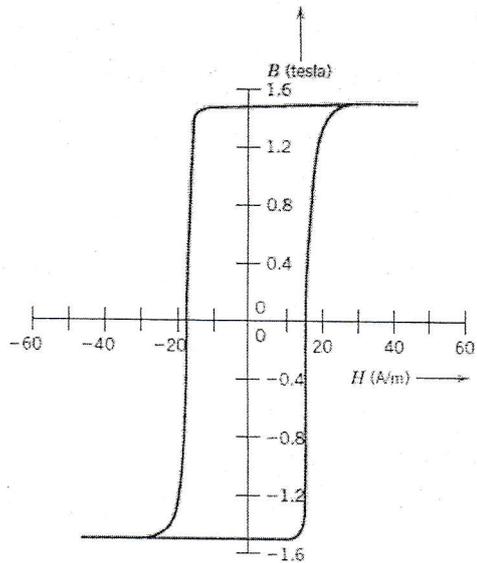


Table (1).
The wave length for some color

| Color | Violet | Blue | Green | Yellow | Orange | Red |
|----------------|--------|-----------|-----------|-----------|-----------|------|
| λ (nm) | >450 | 450 - 500 | 500 - 570 | 590 - 870 | 590 - 610 | <610 |

.....GOOD LUCK.....